



$a = \frac{dv}{dt} \approx \frac{v_d}{\tau}$ in between collisions
 Also $eF = ma \rightarrow -eE = m \frac{v_d}{\tau}$
 $v_d = \frac{-e\tau}{m} E$

electron accelerates for a bit, but then scatters in some random direction (resetting velocity)

Net effect = some small "drift velocity", $v_{drift} \sim E$

$$\frac{\text{current}}{\text{area}} = \left(\frac{\text{electrons}}{\text{volume}} \right) \left(\frac{\text{charge}}{\text{electron}} \right) \left(\frac{\text{length}}{\text{time}} \right)$$

$$J = n(-e) v_{drift}$$

\downarrow
 $= -\frac{e\tau}{m} E$ from above

so $J = \frac{ne^2\tau}{m} E$

$$J = \sigma E$$

↳ electrical conductivity

Back to thermal conductivity

Back in Phys 123

$$\frac{Q}{t} = \frac{k A \Delta T}{\text{length}}$$

↙ thermal conductivity

$$k \text{ (W/mK)} = \frac{Q}{A t} = -k \frac{dT}{dx}$$

↳ so flow is in right direction
 ↳ flux of thermal energy

Where does it come from? Something: phonon scattering

if no scattering, get "ballistic transport," leads to very different situation

Scattering:

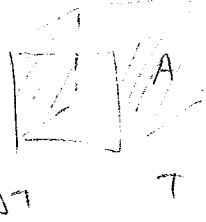
$$\tau = \text{ave scattering time (assume it exists)}$$

$$\lambda = \text{mean free path (distance between scattering events)}$$

$$v_{rms} = \frac{\lambda}{\tau}$$

Assume $\tau =$ independent of phonon energy

Δx distance between scattering events $= v_x \tau$



$n = \frac{\# \text{ phonons}}{\text{volume}}$ (like n for electrons)
 ↳ poor label, but what it means

$n v_x = \frac{\# \text{ phonons}}{\text{area} \times \text{time}} = \text{"phonon flux"}$

Energy transport $\tilde{C}_V = \text{heat capacity for same phonons} = \frac{C_V}{N}$
 ie. $Q = \tilde{C}_V \Delta T$

may be 3 orders in reverse order since j_u is on forward path

$j_u = \frac{\text{energy lost from box}}{\text{area} \times \text{time}} = - \left(n v_x \right) \left(\tilde{C}_V \Delta T \right)$
 $\frac{\Delta \text{ heat}}{\text{area} \times \text{time}} = \frac{\text{energy}}{\text{area} \times \text{time}}$

Thermal energy flux

Also: $\Delta T = \text{gradient} \frac{dT}{dx} \times \Delta x$

$\Delta T = \frac{dT}{dx} \times \underbrace{(v_x \tau)}_{L = \Delta x}$
 $\tau = \text{time between scattering events}$

$j_u = - n v_x^2 \tilde{C}_V \tau \frac{dT}{dx}$
 $= - \frac{1}{3} n v^2 \tilde{C}_V \tau \frac{dT}{dx}$

$\langle v_x^2 \rangle = \frac{1}{3} \langle v^2 \rangle$
 $\underbrace{(v \tau)}_{\ell} = \ell$ mean free path
 $\underbrace{(n \tilde{C}_V)}_{C} = \frac{\text{phonos}}{\text{volume}} \cdot \frac{\text{heat cap}}{\text{phonon}}$

$\approx C = \frac{\text{heat cap}}{\text{volume}}$ ie $Q = VC \Delta T$
 ↳ (oops symbol!)

$j_u = - \frac{1}{3} C v \ell \frac{dT}{dx}$

Compare of previous page, means that

$k = \frac{1}{3} C v \ell$
Thermal

Table 2 pg 122 some representative values of C, K, and ℓ (for $v = 5000 \text{ m/s}$ as typical velocity)

What contributes to scattering?

- defects / surface
- electrons
- other phonons

→ side notes: λ is limited by isotopes, which seem to be "defects" to the phonons called "isotope effect"

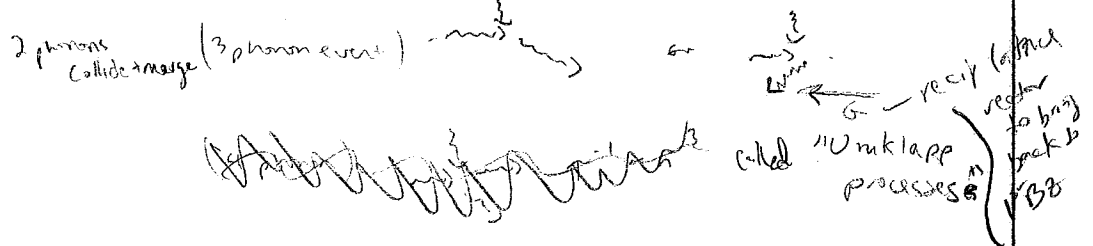
Case 1: low temp, recall $C \sim T^3$

+ not many other phonons present, λ is limited by defects/sur^{face}, expect λ independent of temp

Then $K = \frac{1}{2} C v \lambda$ const

expect $K \sim T^3$ seen in Fig 18, 19 pg 127 NaF, Ge

Case 2 high temp, recall $C \sim const$. But λ is no longer const. phonon-phonon scattering $\lambda^{-1} \sim n^2$ (prob. of 2 phonons)



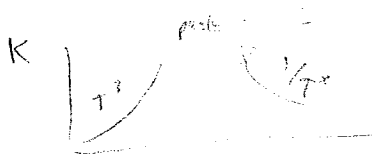
$$n = \frac{1}{e^{h\nu/kT} - 1}$$

if T is high, this is small

$$= \frac{1}{1 + \frac{h\nu}{kT}} \approx \frac{kT}{h\nu}$$

$\lambda^{-1} \propto \frac{1}{T^2}$ $x \leq 2$, possibly down to 1 from experiments

$$K = \frac{1}{2} C v \lambda \Rightarrow K \sim \frac{1}{T^x}$$



again, seen in Fig 18, 19 pg 127

Not quite "high" → the Boltzmann factor governs how many phonons have high energy $\frac{1}{e^{h\nu/kT}}$

Jan 29 03/4

Chapter 6 Electrons!

plan of attack

- Ch 6 "Free electron Fermi gas" - no crystal structure (mostly explains metals)
- Ch 7 "Nearly free electron model" - band minimum structure (periodic)

Ch 7, cont. more complete band structure

Ch 8 Semiconductors (and insulators)

↳ semiconductors that just don't know it yet ☺

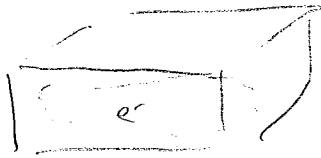
~~XXXXXXXXXX~~

Then ends + ends - optical properties

- etc.

Tyler + me out of town
Mon = Dr. VanHout
Wed = Dr. Daving

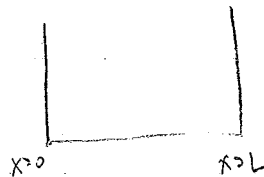
Free electrons - Lorentz quote on pg 133



electrons confined in a box (the crystal)

intro

phys 222



infinite square well

$$H\psi = E\psi$$

$$-\frac{\hbar^2}{2m} \frac{d^2}{dx^2}$$

(Eigenvalue problem)

results: $\psi_n = A \sin \frac{n\pi x}{L}$ are wavefunctions (Eigenfunctions)

satisfies $\psi(x=0) = 0$
and $\psi(x=L) = 0$

plug into eqn

$$-\frac{\hbar^2}{2m} \left(-\left(\frac{n\pi}{L}\right)^2 \right) \psi = E \psi$$

$$\boxed{E = \frac{\hbar^2 n^2 \pi^2}{2m L^2}}$$

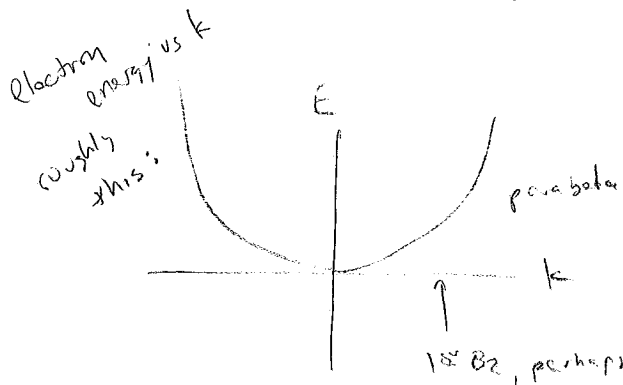
but note $\sin \frac{0 \cdot \pi x}{L}$
 \downarrow
 $k = \frac{0 \cdot \pi}{L}$

$$E = \frac{\hbar^2 k^2}{2m}$$

Compare $E = \frac{1}{2} m v^2 = \frac{(m v)^2}{2m} = \frac{p^2}{2m}$

if $p = \hbar k$ then that energy eqn makes sense

same as momentum of wave



Note: for phonon dispersion curve repeated because of lattice periodicity

Here we haven't made that assumption yet. (But we will!)

(And same result!)



- periodic dispersion
- finite points separated by $2\pi/L$ crystal dimension

(end of intro)

Classical States

3-D

discrete energy levels

$$D(k) = \left(\begin{matrix} 2 \\ \uparrow \\ \text{spin states} \end{matrix} \right) \frac{4\pi k^2}{dE/dk}$$

$$E = \frac{\hbar^2 k^2}{2m} \rightarrow \frac{dE}{dk} = \frac{2\hbar^2 k}{2m} = \frac{\hbar^2 k}{m} = \frac{\hbar^2}{m} \sqrt{\frac{2mE}{\hbar^2}}$$

$$D(E) = \frac{2 \cdot 4\pi \left(\frac{2mE}{\hbar^2} \right)^{3/2}}{\frac{\hbar^2}{m} \sqrt{\frac{2mE}{\hbar^2}}} \times \frac{V}{(2\pi)^3}$$

$$D(E) = \frac{1}{2\pi^2} \left(\frac{2m}{\hbar^2} \right)^{3/2} E^{1/2}$$

factor of 2: $\frac{16}{\sqrt{2} \cdot 8} = \frac{2}{\sqrt{2}} = \sqrt{2}$

$\frac{2^{3/2}}{2} = 2^{1/2} = \sqrt{2}$

yes, the same